Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSIV)

# **TPCF8104**

Notebook PC Applications
Portable Equipment Applications

- Low drain-source ON resistance: R<sub>DS</sub> (ON) = 21 mΩ (typ.)
- High forward transfer admittance: |Yfs| = 9.6 S (typ.)
- Low leakage current:  $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -30 \text{ V)}$
- Enhancement mode:  $V_{th} = -0.8$  to -2.0 V ( $V_{DS} = -10$  V,  $I_D = -1$ mA)

# 0.3 +0.11 -0.05 0.3 +0.11 -0.05 0.8 ± 0.

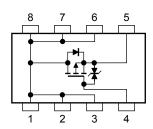
Weight: 0.011 g (typ.)

**TOSHIBA** 

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V <sub>DSS</sub>	<del>-</del> 30	X
Drain-gate voltage (R <sub>GS</sub> = 20 kΩ)			$V_{DGR}$	)) –30	V
Gate-source voltage			VGSS	±20	V
Drain current	DC	(Note 1)	(ID))	-6	
Diain current	Pulse	(Note 1)	IDP	-24	
Drain power dissipation (t = 5 s) (Note 2a)			PD	2.5	∜ <sub>W</sub>
Drain power dissipation (t = 5 s) (Note 2b)			7 PD	0.7	W
Single pulse avalanche energy (Note 3)			EAS	5.8	mJ
Avalanche current			I <sub>AR</sub>	-3	Α
Repetitive avalanche energy (Note 4)			FAR	0.25	mJ
Channel temperature			√T <sub>oh</sub>	150	°C
Storage temperature range			T <sub>stg</sub>	–55 to 150	°C

### **Circuit Configuration**



2-3U1A

Note: (Note 1), (Note 2), (Note 3) and (Note 4): See the next page.

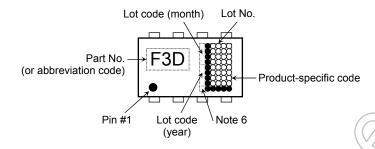
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Please handle with caution.

### **Thermal Characteristics**

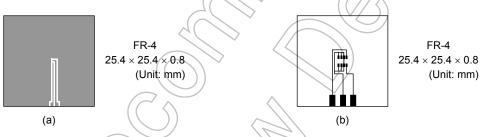
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 5 s) (Note 2a)	R <sub>th (ch-a)</sub>	50.0	°C/W
Thermal resistance, channel to ambient (t = 5 s) (Note 2b)	R <sub>th (ch-a)</sub>	178.6	°C/W

### Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (b) Device mounted on a glass-epoxy board (b)



Note 3:  $V_{DD} = -24 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial), L = 0.5 mH,  $R_G = 25 \Omega$ ,  $I_{AR} = -3.0 \text{ A}$ 

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: • on the lower left of the marking indicates Pin 1.

Note 6: A dot marking identifies the indication of product Labels.

Without a dot: [[Pb]]/INCLUDES > MCV

With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

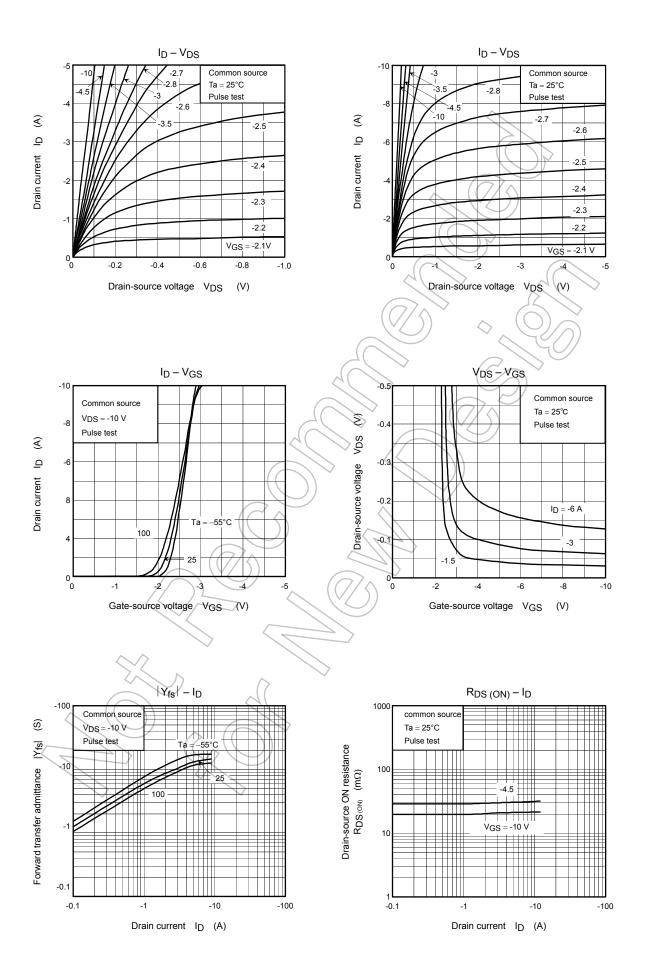
2

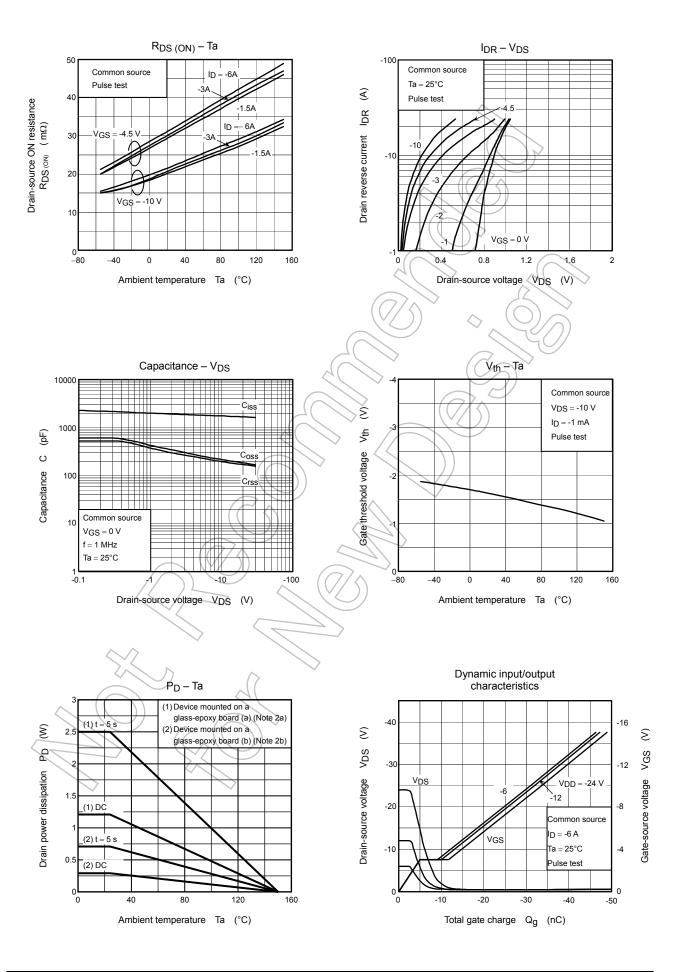
# **Electrical Characteristics (Ta = 25°C)**

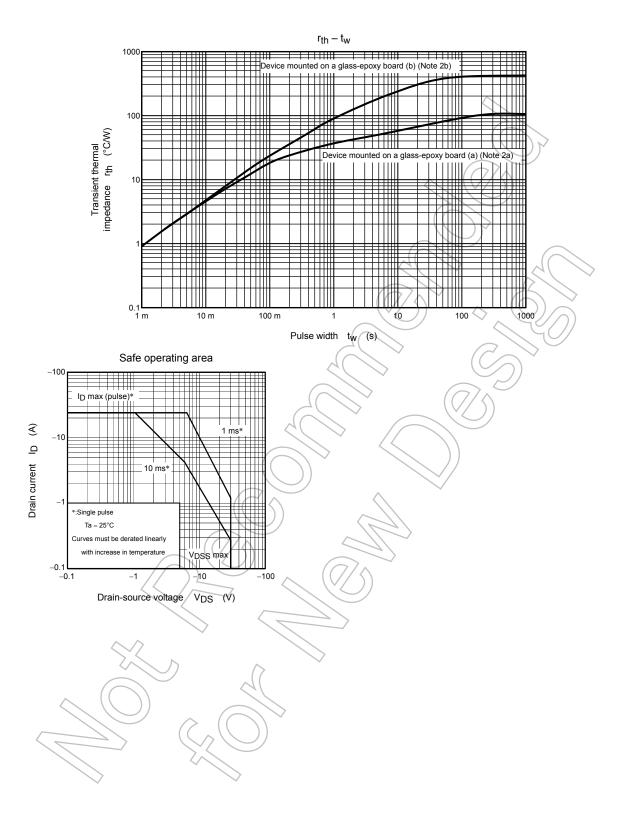
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	— <u>±</u> 10		μА	
Drain cut-off curre	ent	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	_	— -10		μА
Drain-source breakdown voltage		V <sub>(BR) DSS</sub>	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30	_	_	V
		V <sub>(BR)DSX</sub>	$I_D = -10 \text{ mA}, V_{GS} = 20 \text{ V}$	-15		_	V
Gate threshold vo	oltage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_D = -1 \text{mA}$	-0.8	) /_	-2.0	٧
Drain-source ON resistance		Б	$V_{GS} = -4.5 \text{ V}, I_D = -3.0 \text{ A}$	)    -  -	29	38	- mΩ
		R <sub>DS</sub> (ON)	$V_{GS} = -10 \text{ V}, I_D = -3.0 \text{A}$	$\rightarrow$	21	28	
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_D = -3.0 \text{A}$	4.8	9.6	_	S
Input capacitance	9	C <sub>iss</sub>		_	1760	_	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	200	_	pF
Output capacitance		Coss		_ /	210	$\searrow$	
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 0 V 7   V <sub>D</sub> +3.0 A	-(	2.8		
	Turn-on time	t <sub>on</sub>	-10 V		12	_	
	Fall time	t <sub>f</sub>	R = 1	$(\mathcal{I})$	22	_	ns
	Turn-off time	toff	$V_{DD} \simeq -15 V$ Duty $\leq 1\%$ , $t_W = 10 \mu s$	) —	90	_	
Total gate charge (gate-source plus gate-drain)		Qg	V <sub>DD</sub> ~ -24 V, V <sub>GS</sub> = -10V,		34		
Gate-source charge1		Q <sub>gs1</sub>	$I_D = -6.0 \text{ A}$	_	4.7	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>			7.2	_	

# Source-Drain Ratings and Characteristics (Ta = 25°C)

Charact	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	I <sub>DRP</sub>	_	_	_	-24	А
Forward voltage	(diode)	V <sub>DSF</sub>	$I_{DR} = -6.0 \text{ A}, V_{GS} = 0 \text{ V}$		_	1.2	V







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